

Silicon Diode

BYV28-600

600V/3.1A

DATASHEET

OEM – Philips

Source: Philips Databook 1999

Ultra fast low-loss controlled avalanche rectifiers

BYV28 series

FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack
- Also available with preformed leads for easy insertion.

DESCRIPTION

Rugged glass SOD64 package, using a high temperature alloyed construction.

This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



Fig.1 Simplified outline (SOD64) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	repetitive peak reverse voltage				
	BYV28-50		–	50	V
	BYV28-100		–	100	V
	BYV28-150		–	150	V
	BYV28-200		–	200	V
	BYV28-300		–	300	V
	BYV28-400		–	400	V
	BYV28-500 BYV28-600		–	500 600	V
V_R	continuous reverse voltage				
	BYV28-50		–	50	V
	BYV28-100		–	100	V
	BYV28-150		–	150	V
	BYV28-200		–	200	V
	BYV28-300		–	300	V
	BYV28-400		–	400	V
	BYV28-500 BYV28-600		–	500 600	V
$I_{F(AV)}$	average forward current	$T_{tp} = 85\text{ °C}$; lead length = 10 mm; see Figs 2 and 3;	–	3.5	A
	BYV28-50 to 400 BYV28-500 and 600	averaged over any 20 ms period; see also Figs 10 and 11	–	3.1	A
$I_{F(AV)}$	average forward current	$T_{amb} = 60\text{ °C}$; printed-circuit board mounting (see Fig.20);	–	1.9	A
	BYV28-50 to 400 BYV28-500 and 600	see Figs 4 and 5; averaged over any 20 ms period; see also Figs 10 and 11	–	1.5	A

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SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{FRM}	repetitive peak forward current	$T_{ip} = 85\text{ °C}$; see Figs 6 and 7	-	32	A
	BYV28-50 to 400			31	A
I_{FRM}	repetitive peak forward current	$T_{amb} = 60\text{ °C}$; see Figs 8 and 9	-	17	A
	BYV28-50 to 400			16	A
I_{FSM}	non-repetitive peak forward current	$t = 10\text{ ms}$ half sine wave; $T_j = T_{j\text{max}}$ prior to surge; $V_R = V_{RRM\text{max}}$	-	90	A
E_{RSM}	non-repetitive peak reverse avalanche energy	$L = 120\text{ mH}$; $T_j = T_{j\text{max}}$ prior to surge; inductive load switched off	-	20	mJ
T_{stg}	storage temperature		-65	+175	°C
T_j	junction temperature	see Fig.12	-65	+175	°C

ELECTRICAL CHARACTERISTICS $T_j = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT		
V_F	forward voltage	$I_F = 3.5\text{ A}$; $T_j = T_{j\text{max}}$; see Figs 13, 14 and 15	-	-	0.80	V		
	BYV28-50 to 200				0.83	V		
	BYV28-300 and 400				0.98	V		
V_F	forward voltage	$I_F = 3.5\text{ A}$; see Figs 13, 14 and 15	-	-	1.02	V		
	BYV28-50 to 200				1.05	V		
	BYV28-300 and 400				1.25	V		
$V_{(BR)R}$	reverse avalanche breakdown voltage	$I_R = 0.1\text{ mA}$						
	BYV28-50				55	-	-	V
	BYV28-100				110	-	-	V
	BYV28-150				165	-	-	V
	BYV28-200				220	-	-	V
	BYV28-300				330	-	-	V
	BYV28-400				440	-	-	V
	BYV28-500				560	-	-	V
I_R	reverse current	$V_R = V_{RRM\text{max}}$; see Fig.16	-	-	5	μA		
		$V_R = V_{RRM\text{max}}$; $T_j = 165\text{ °C}$; see Fig.16	-	-	150	μA		
t_{rr}	reverse recovery time	when switched from $I_F = 0.5\text{ A}$ to $I_R = 1\text{ A}$; measured at $I_R = 0.25\text{ A}$; see Fig.22	-	-	25	ns		
					BYV28-50 to 200	50	ns	
	BYV28-300 to 600							

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
C_d	diode capacitance	$f = 1 \text{ MHz}; V_R = 0;$ see Figs 17, 18 and 19	-	190	-	pF
	BYV28-50 to 200		-	150	-	pF
	BYV28-300 and 400 BYV28-500 and 600		-	125	-	pF
$\left \frac{dI_R}{dt} \right $	maximum slope of reverse recovery current	when switched from $I_F = 1 \text{ A}$ to $V_R \geq 30 \text{ V}$ and $dI_F/dt = -1 \text{ A}/\mu\text{s}$; see Fig.21	-	-	4	A/ μs

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th \text{ j-tp}}$	thermal resistance from junction to tie-point	lead length = 10 mm	25	K/W
$R_{th \text{ j-a}}$	thermal resistance from junction to ambient	note 1	75	K/W

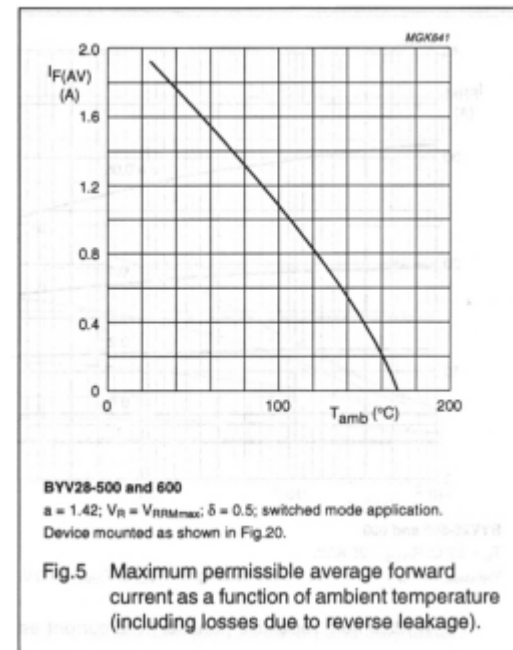
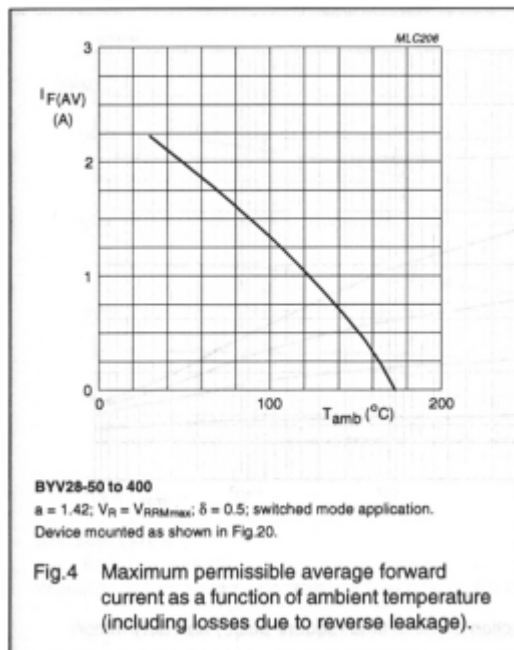
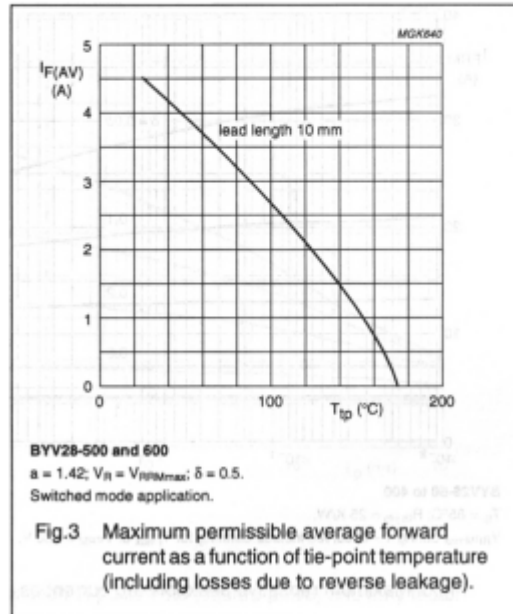
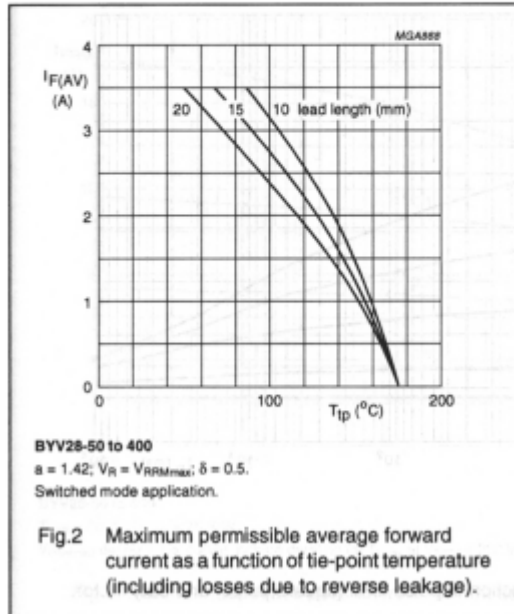
Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer $\geq 40 \mu\text{m}$, see Fig.20
For more information please refer to the 'General Part of Handbook SC01'.

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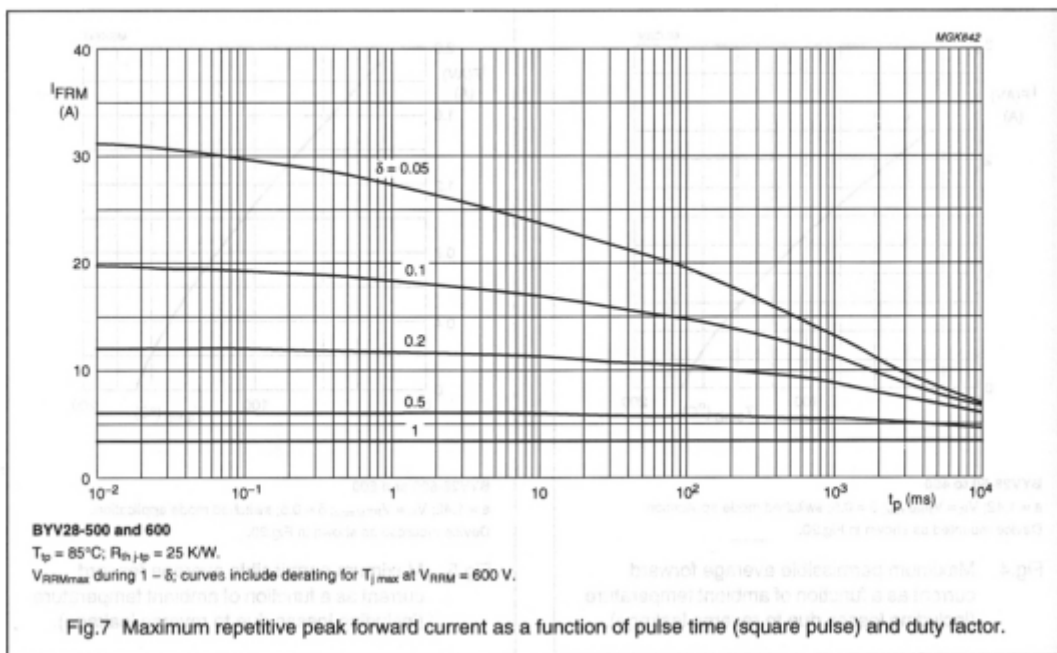
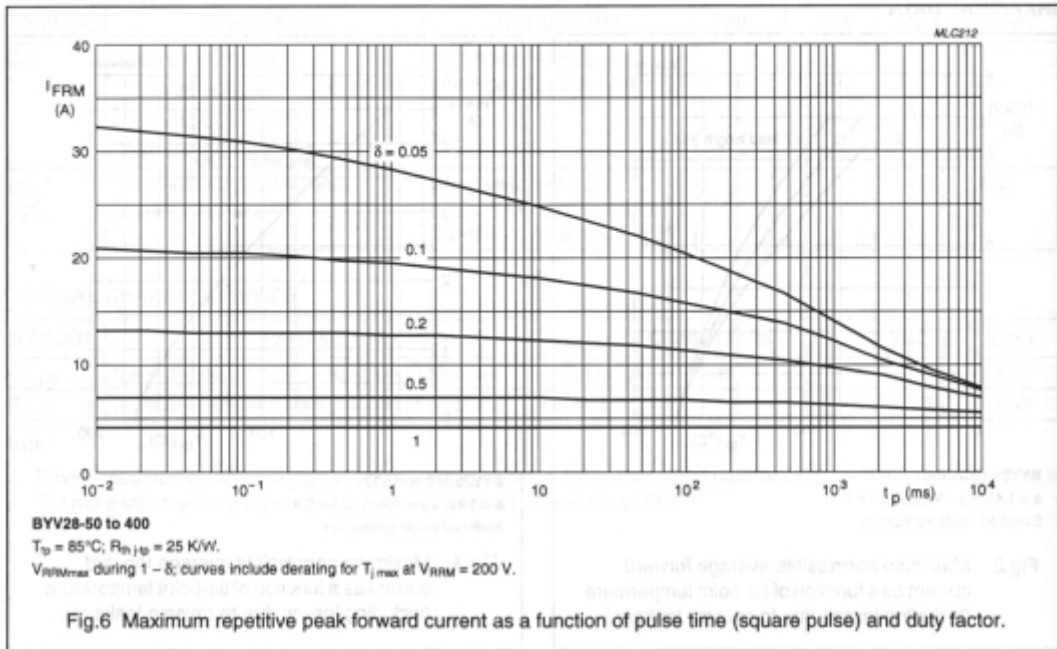
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GRAPHICAL DATA



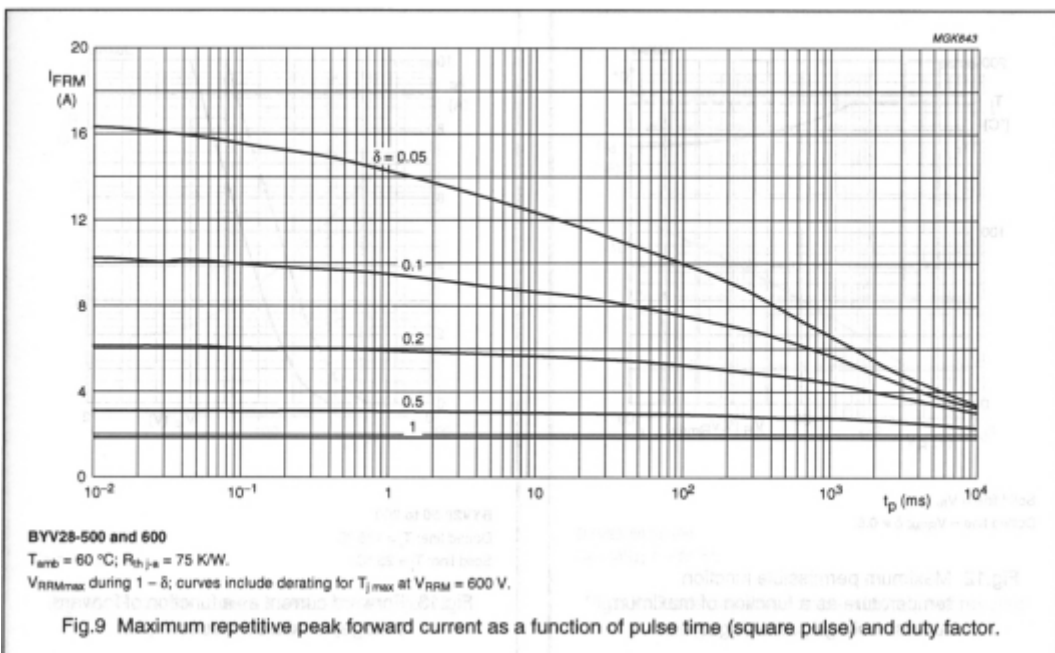
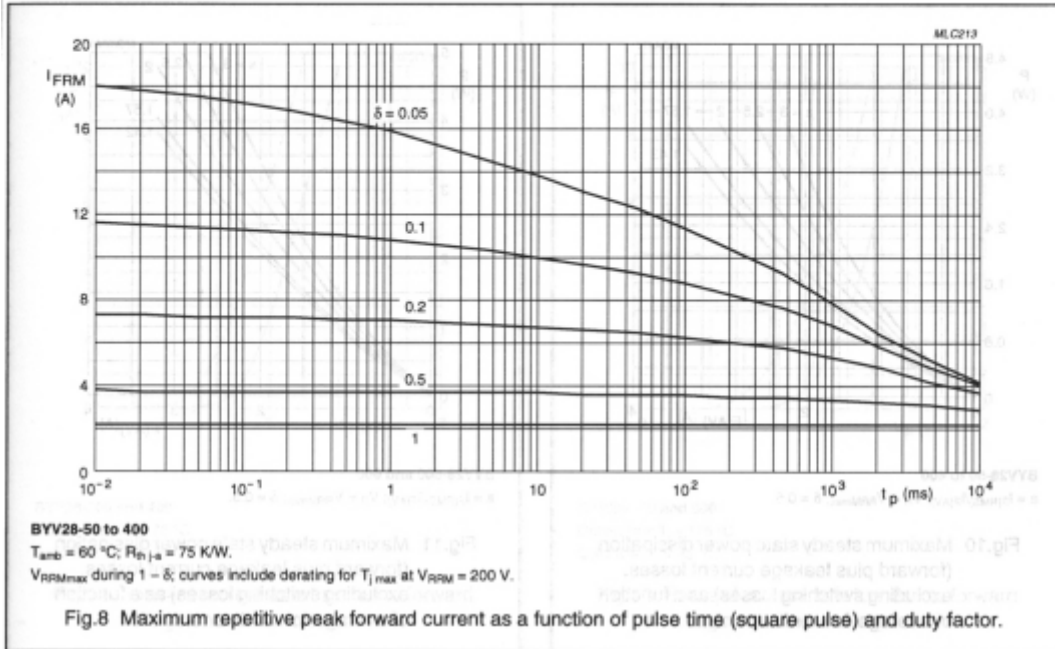
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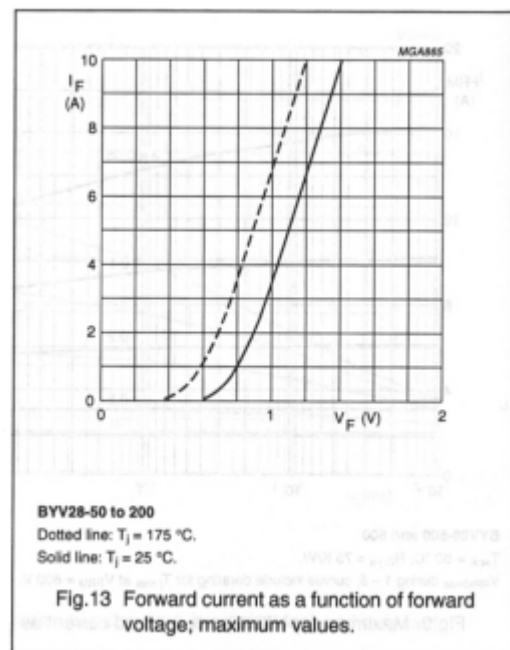
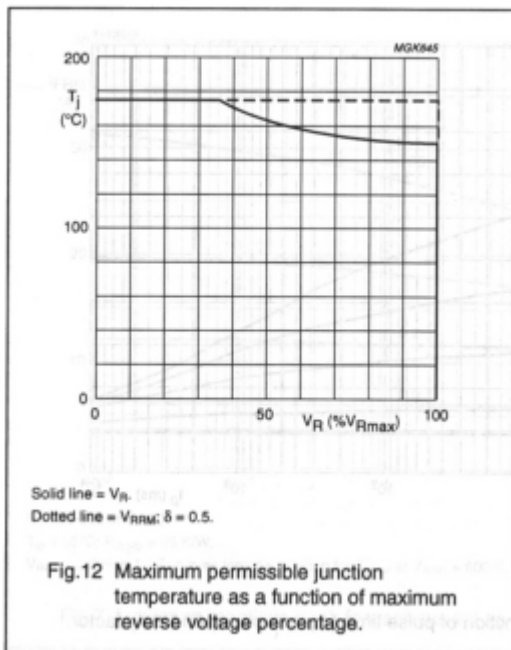
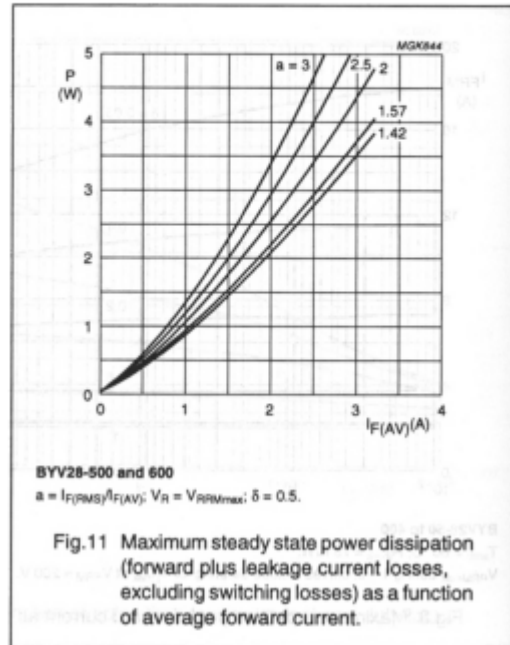
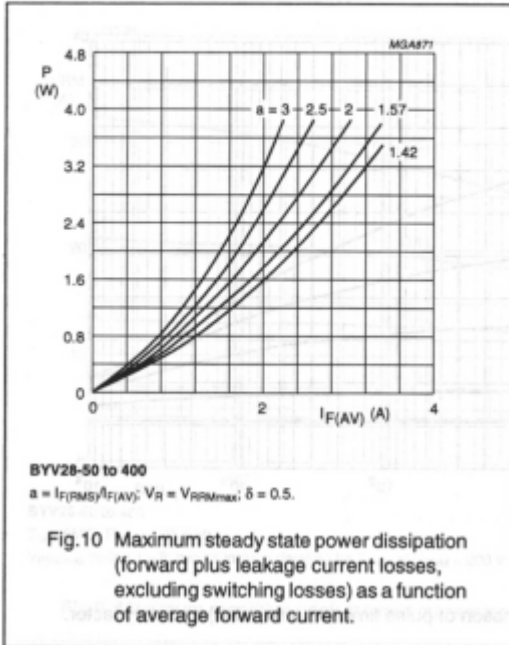
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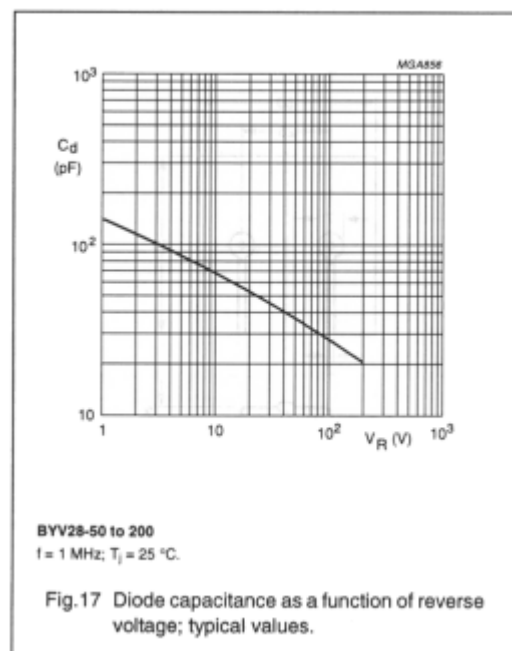
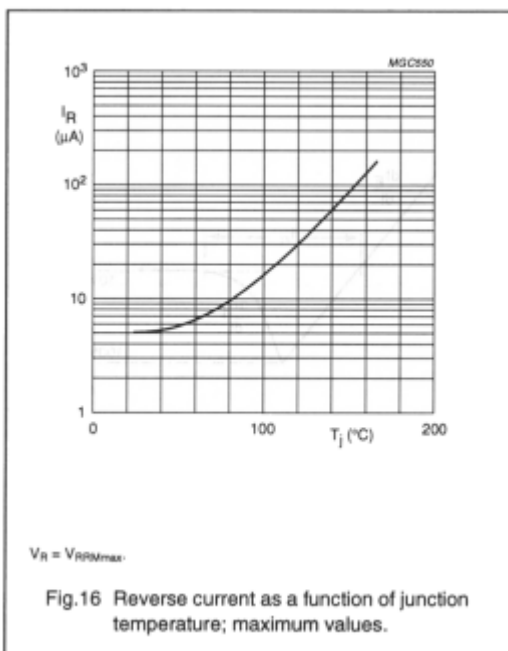
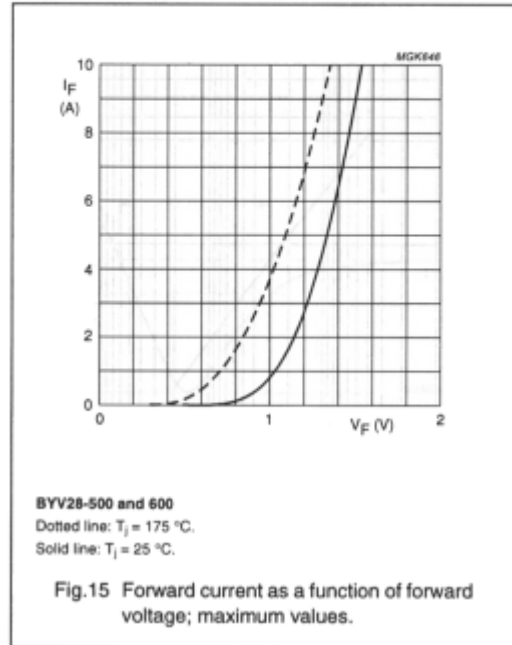
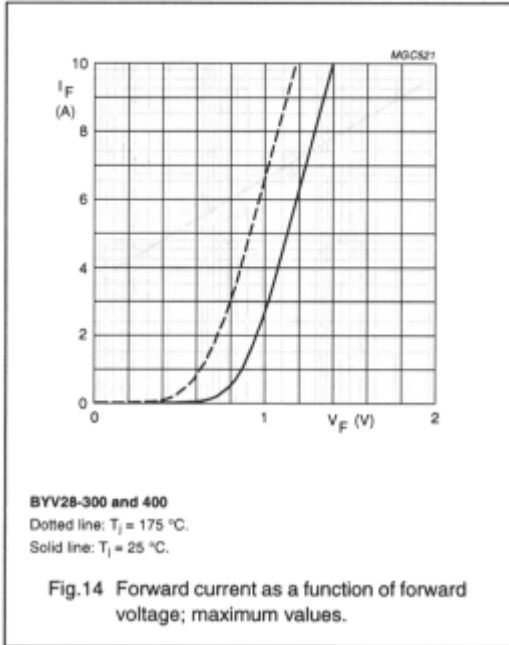
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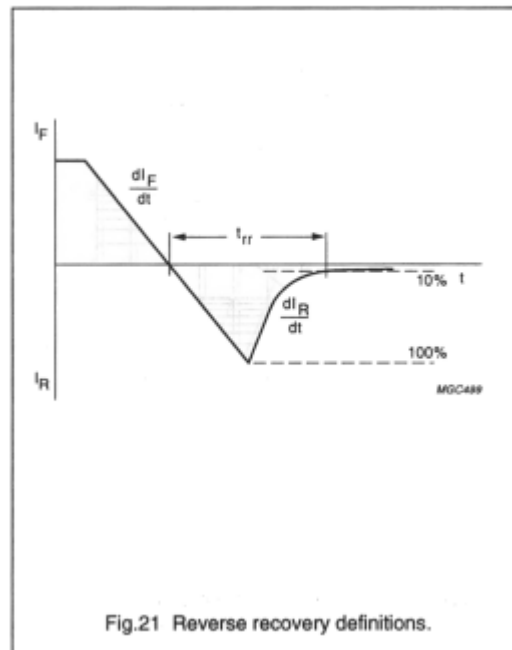
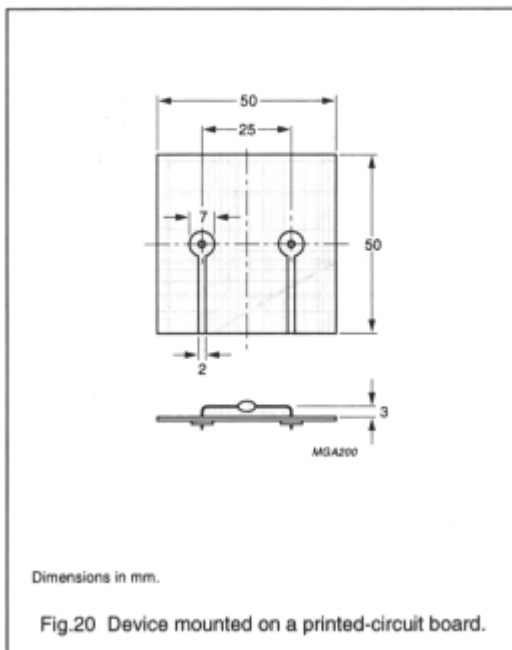
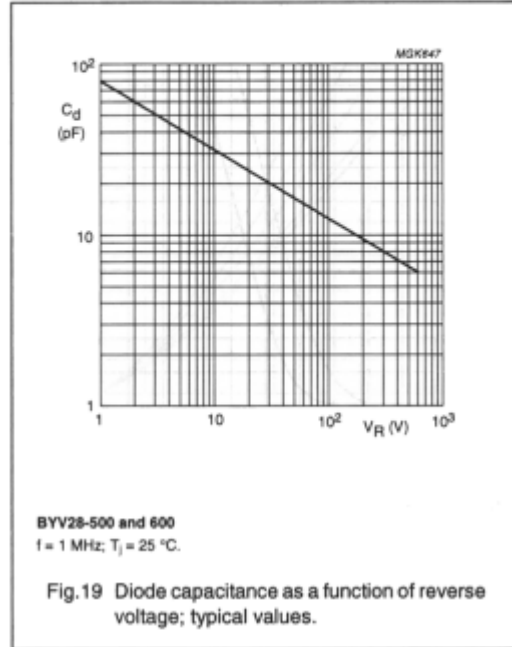
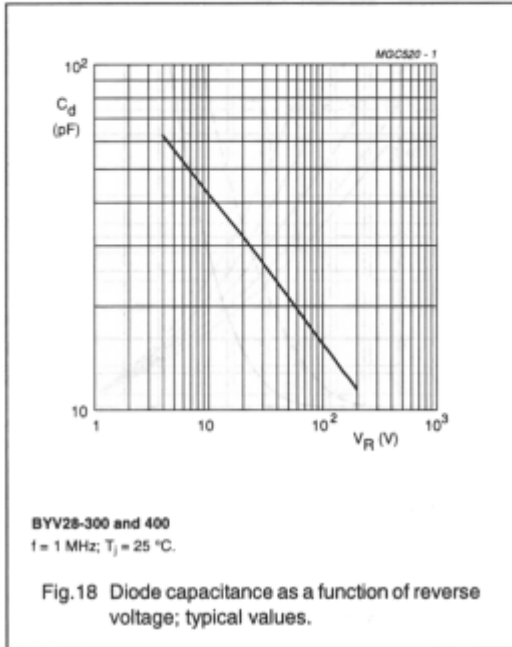
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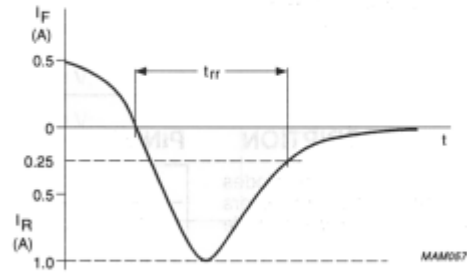
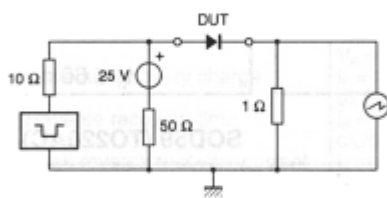
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Input impedance oscilloscope: 1 M Ω , 22 pF; $t_i \leq 7$ ns.
Source impedance: 50 Ω ; $t_s \leq 15$ ns.

Fig.22 Test circuit and reverse recovery time waveform and definition.